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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Benjamin A. Haskell et al. Examiner: Michael P. Lulis
Serial No.: 10/537,385 Group Art Unit: 2824
Filed: June 3, 2005 Docket: G&C 30794.94-US-WO
Title: GROWTH OF PLANAR, NON-POLAR GALLIUM NITRIDE BY HYDRIDE
VAPOR PHASE EPITAXY

AMENDMENT UNDER 37 C.F.R. §1.111

MAIL STOP AMENDMENT
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

In response to the Office Action dated July 2, 2007, please amend the above-identified application as follows.